

General Description

The MAX4599 single-pole/double-throw (SPDT) switch operates from a +2.0V to +5.5V single supply. It offers 60Ω max on-resistance (R_{ON}) at +5V and fast switching times ($t_{ON} = 30$ ns max, $t_{OFF} = 25$ ns max).

The MAX4599 features excellent R_{ON} flatness (4 Ω max) and matching (1Ω max) between channels. This device also offers 5pC max charge injection.

The MAX4599 is available in tiny 6-pin SC70, µDFN, and SOT23 packages.

Applications

Battery-Operated Equipment Audio and Video Signal Routing Cellular Phones Low-Voltage Data-Acquisition Systems Sample-and-Hold Circuits Communications Circuits

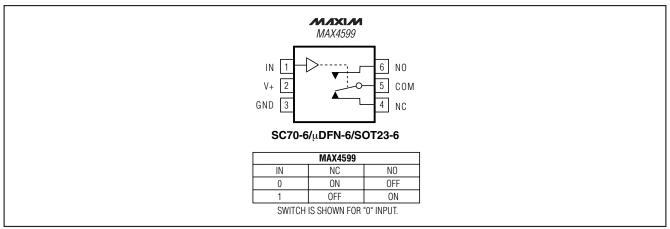
Features

- ♦ Available in 6-Pin SC70 Package
- ♦ 60Ω max (40Ω typ) On-Resistance
- ♦ 1Ω max (0.2Ω typ) Ron Matching Between Channels
- \blacklozenge 4 Ω max (2.5 Ω typ) Ron Flatness
- ♦ Fast Switching: toN = 30ns (max) toff = 25ns (max)
- ♦ Guaranteed 5pC max Charge Injection
- ♦ +2.0V to +5.5V Single-Supply Operation
- ♦ 200MHz -3dB Bandwidth
- ♦ Low ±0.5nA Leakage Current at +25°C
- ♦ Break-Before-Make Switching
- **♦ TTL/CMOS-Logic Compatible**
- ♦ -76dB Off-Isolation at 1MHz
- ♦ 0.12% Total Harmonic Distortion

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4599EXT-T	-40°C to +85°C	6 SC70-6	AAF
MAX4599EUT-T	-40°C to +85°C	6 SOT23-6	AAHC
MAX4599ELT-T	-40°C to +85°C	6 µDFN-6	AA

Pin Configuration/Functional Diagram/Truth Table



MIXIM

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to GND	Continuous Power Dissipation ($T_A = +70^{\circ}C$)
V+0.3V to +6V	6-Pin SC70-6 (derate 3.1mW/°C above +70°C)245mW
IN, COM, NO, NC (Note 1)0.3V to (V+ + 0.3V)	6-Pin µDFN-6 (derate 2.1mW/°C above +70°C)168mW
Continuous Current (any terminal)±20mA	6-Pin SOT23-6 (derate 7.1mW/°C above +70°C)571mW
Peak Current, COM, NO, NC	Operating Temperature Range
(pulsed at 1ms, 10% duty cycle)±40mA	MAX4599E_T40°C to +85°C
	Storage Temperature Range65°C to +150°C
	Lead Temperature (soldering, 10s)+300°C

Note 1: Signals on NO, NC, COM, or IN exceeding V+ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS— Single +5V Supply

(V+ = +4.5V to +5.5V, V_{INH} = +2.4V, V_{INL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH	•		1				
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On-Resistance	Ron	$V+ = 4.5V$, $I_{COM} = 1mA$,	T _A = +25°C		40	60	Ω
on resistance	TION	V_{NO} or $V_{NC} = 3.5V$	$T_A = T_{MIN}$ to T_{MAX}			65	30
On-Resistance Match Between	ARON	$V+ = 4.5V$, $I_{COM} = 1A$,	T _A = +25°C		0.2	1	Ω
Channels (Note 4)	AHON	V_{NO} or $V_{NC} = 3.5V$	$T_A = T_{MIN}$ to T_{MAX}			2	52
On-Resistance Flatness	R _{FLAT} (ON)	$V+ = 4.5V$; $I_{COM} = 1mA$; V_{NO} or $V_{NC} = 1V$, 2.0V,	T _A = +25°C		2.5	4	Ω
(Note 5)	I TELAT(ON)	3.5V	$T_A = T_{MIN}$ to T_{MAX}			5	22
NO, NC Off-Leakage Current	I _{NO(OFF)} ,	100000 4.5V, VNO OF VNC = 4.5V,	, · ·	-0.5	0.01	0.5	nA
(Note 6)	I _{NC} (OFF)		$T_A = T_{MIN}$ to T_{MAX}	-5		5	IIA
COM On-Leakage Current	Icom(on)	$V_{\text{COM}(ON)}$ $V_{\text{COM}} = 1V,$ $V_{\text{COM}} = $	T _A = +25°C	-1	0.01	1	nA
(Note 6)	ICOM(ON)		-10		10	I IIA	
DIGITAL I/O							
Input Logic High	VIH			2.4			V
Input Logic Low	V _{IL}					0.8	V
DYNAMIC	,		<u> </u>				
Turn-On Time	ton	V_{NO} , $V_{NC} = 3V$; $R_L = 1k\Omega$; $C_L = 35pF$;	T _A = +25°C		25	30	ns
		Figure 2 $T_A = T_{MIN}$ to T_{MAX}				40	110

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

 $(V+=+4.5V \text{ to } +5.5V, V_{INH}=+2.4V, V_{INL}=+0.8V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.})$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIO	ONS	MIN	TYP	MAX	UNITS
Turn-Off Time		V _{NO} , V _{NC} = 3V;	T _A = +25°C		20	25	
Tum-Oil Time	toff	$R_L = 1k\Omega$; $C_L = 35pF$; Figure 2	$T_A = T_{MIN}$ to T_{MAX}			30	ns
Break-Before-Make	t _{BBM}	$V_{NO}, V_{NC} = 3V;$ $R_{I} = 1k\Omega; C_{I} = 35pF;$	T _A = +25°C		10		
Dieak-Deloie-Wake	rbbivi	Figure 3	TA = TMIN to TMAX	1			ns
On-Channel -3dB Bandwidth	BW	Signal = 0dBm, 50Ω in and out, Figure 5	T _A = +25°C		200		MHz
Off-Isolation (Note 7)	V _{ISO}	$C_L = 5pF; R_L = 50\Omega;$ $f = 1MHz; V_{NO}, V_{NC} = 1V_{RMS}; Figure 5$	T _A = +25°C		-76		dB
Charge Injection (Note 6)	Q	V _{GEN} = 0, R _{GEN} = 0, C _L = 1.0nF, Figure 4	T _A = +25°C		3	5	рС
NO, NC Off-Capacitance	C _{NO(OFF}), C _{NC(OFF})	V _{NO} , V _{NC} = GND; f = 1MHz; Figure 6	T _A = +25°C		8		pF
COM Off-Capacitance	C _{COM} (OFF)	V _{COM} = GND, f = 1MHz, Figure 6	T _A = +25°C		8		pF
Switch On-Capacitance	C _(ON)	V _{COM} = V _{NO} , V _{NC} = GND, f = 1MHz, Figure 6	T _A = +25°C		20		рF
Total Harmonic Distortion	THD	$R_L = 600\Omega$, $V_{IN} = 5Vp-p$, $f = 20Hz$ to $20kHz$	T _A = +25°C		0.12		%
SUPPLY						•	
Power-Supply Range	V+			2.0		5.5	V
Positive Supply Current	l+	$V+ = 5.5V$, $V_{IN} = 0$ or $V+$		-1	0.001	1	μΑ

ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V+ = +2.7V \text{ to } +3.6V, V_{INH} = +2.0V, V_{INL} = +0.8V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.})$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	٧
On-Resistance	Ron	V+ = 2.7V, I _{COM} = 1mA, V _{NO} or V _{NC} = 1V	$T_{+} = 2.7V$, $I_{COM} = 1mA$, $T_{A} = +25$ °C		60	95	Ω
On resistance	TION	V_{NO} or $V_{NC} = 1V$	$T_A = T_{MIN}$ to T_{MAX}			105	20
DIGITAL I/O							
Input Logic High	VIH			2.0			V
Input Logic Low	VIL					0.8	V

ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

(V+ = +2.7V to +3.6V, V_{INH} = +2.0V, V_{INL} = +0.8V, T_A =T_{MIN} to T_{MAX}, unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
DYNAMIC	'						
Turn-On Time	ton	V_{NO} , $V_{NC} = 2V$; $R_L = 1k\Omega$; $C_L = 35pF$;	T _A = +25°C		40	45	ne
Turn-On Time	TON	Figure 2	$T_A = T_{MIN}$ to T_{MAX}			55	- ns
Turn-Off Time	to==	$V_{NO}, V_{NC} = 2V;$ $R_{I} = 1k\Omega; C_{I} = 35pF;$	T _A = +25°C		30	35	ns
Turn-Oil Time	toff	Figure 2	$T_A = T_{MIN}$ to T_{MAX}			40	115
Break-Before-Make		V _{NO} , V _{NC} = 2V;	T _A = +25°C		13		
Dieak-Deloie-Wake	tBBM	$R_L = 1k\Omega$; $C_L = 35pF$; Figure 3	$T_A = T_{MIN}$ to T_{MAX}	1			ns
Charge Injection (Note 6)	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1.0$ nF, Figure 4	T _A = +25°C		2	5	рС
SUPPLY	1	1	,				
Positive Supply Current	l+	$V+ = 3.6V$, $V_{IN} = 0$ or $V+$		-1	0.001	1	μΑ

ELECTRICAL CHARACTERISTICS—Single +2.5V Supply

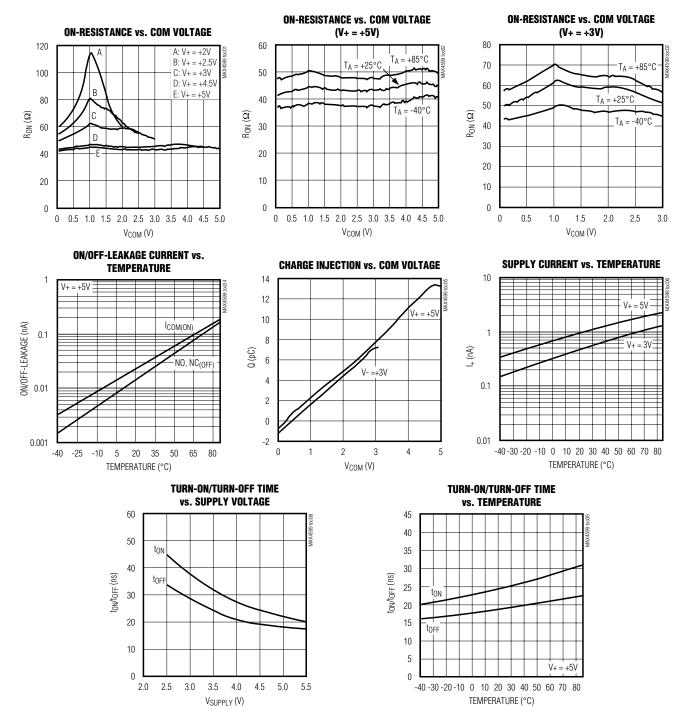
 $(V + = +2.5V, V_{INH} = +2.0V, V_{INL} = +0.6V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.})$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH	1						
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On-Resistance	Ron	$V+ = 2.5V$, $I_{COM} = 1mA$,	T _A = +25°C		65	110	Ω
CTTTCCICtarios	1.014	V_{NO} or $V_{NC} = 1V$	$T_A = T_{MIN}$ to T_{MAX}			120	
Input Logic High	VIH			2.0			V
Input Logic Low	V _{IL}					0.6	V
DYNAMIC							
Turn-On Time	ton	V_{NO} , $V_{NC} = 2V$; $R_{I} = 1k\Omega$; $C_{I} = 35pF$;	T _A = +25°C		45	50	ns
Turn on Time	1011	Figure 3	$T_A = T_{MIN}$ to T_{MAX}			60	110
Turn-Off Time t _{OFF}	V_{NO} , $V_{NC} = 2V$; $R_{I} = 1k\Omega$; $C_{I} = 35pF$;	T _A = +25°C		30	35	ns	
	OFF	Figure 3	$T_A = T_{MIN}$ to T_{MAX}		·	45	110

- Note 2: Parameters are 100% tested at +25°C only and guaranteed by correlation at the full rated temperature.
- **Note 3:** The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.
- Note 4: $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- **Note 5:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.
- Note 6: Guaranteed by design.
- **Note 7:** Off-Isolation = $20\log_{10} (V_{COM} / V_{NO})$, $V_{COM} =$ output, $V_{NO} =$ input to off switch.

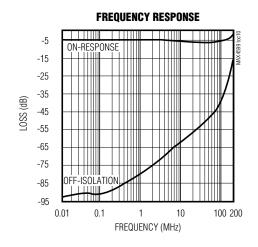
Typical Operating Characteristics

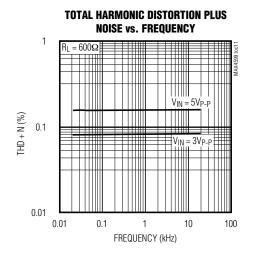
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



Typical Operating Characteristics (continued)

 $(T_A = +25$ °C, unless otherwise noted.)





Pin Description

PIN	NAME	FUNCTION
1	IN	Digital Control Input
2	V+	Positive Supply Voltage
3	GND	Ground
4	NC	Analog Switch Normally Closed
5	COM	Analog Switch Common
6	NO	Analog Switch Normally Open

Applications Information

Analog Signal Levels

Analog signals can range over the supply voltage (V+ to GND) with on-resistance changing very little over the entire range (see *Typical Operating Characteristics*). The MAX4599 is bidirectional, so the NO, NC, and COM pins can be used either as inputs or outputs.

Power-Supply Sequencing and Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+ before applying analog signals or logic inputs, especially if the analog or logic signals are not current limited. If this sequencing is not possible, and if the analog or logic inputs are not current limited to < 20mA, add a small-signal diode (D1) as shown in Figure 1. If the analog signal can dip below GND, add D2. Adding protection diodes

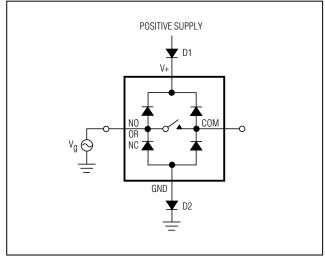


Figure 1. Overvoltage Protection Using Two External Blocking Diodes

reduces the analog signal range to a diode drop (about 0.7V) below V+ for D1 or to a diode drop above ground for D2. The addition of diodes does not affect leakage. On-resistance increases by a small amount at low supply voltages. Maximum supply voltage (V+) must not exceed 6V.

Protection diodes D1 and D2 also protect against some overvoltage situations. A fault voltage up to the absolute maximum rating at an analog signal input does not damage the device, even if the supply voltage is below the signal voltage.

Test Circuits/Timing Diagrams

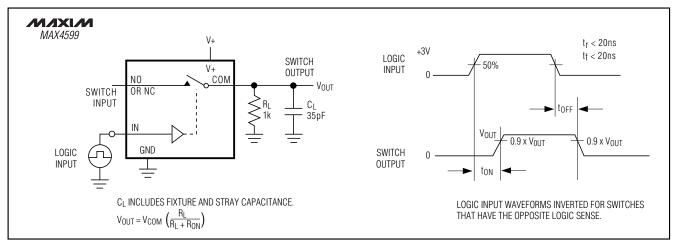


Figure 2. Switching Time

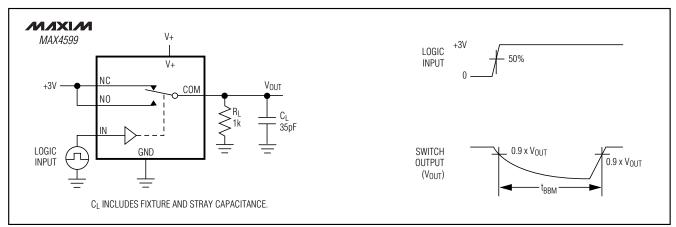


Figure 3. Break-Before-Make Interval

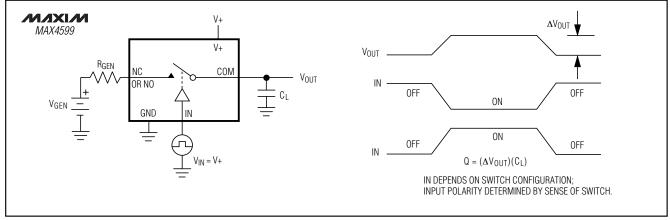


Figure 4. Charge Injection

Test Circuits/Timing Diagrams (continued)

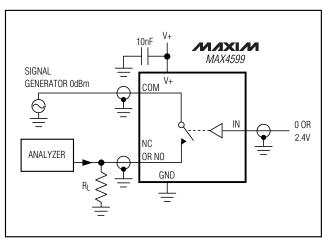


Figure 5. Off-Isolation/On-Channel Bandwidth

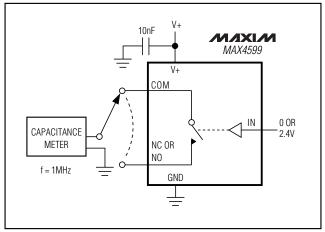


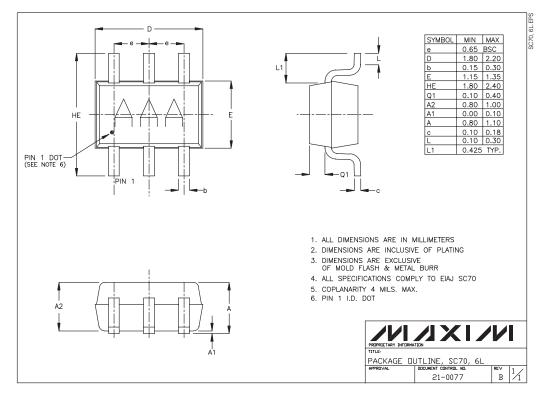
Figure 6. Channel On/Off-Capacitance

Chip Information

TRANSISTOR COUNT: 89

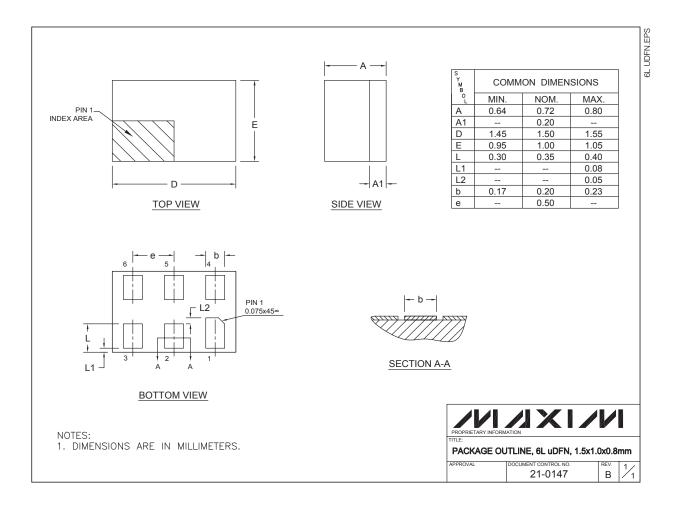
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)



Package Information (continued)

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